- Equivalent Input Noise Voltage 3.5 nV/√Hz
- Unity-Gain Bandwidth . . . 10 MHz Typ
- Common-Mode Rejection Ratio 100 dB Typ
- High DC Voltage Gain . . . 100 V/mV Typ
- Peak-to-Peak Output Voltage Swing
  32 V Typ With V<sub>CC+</sub> = ±18 V and R<sub>L</sub> = 600 Ω
- High Slew Rate . . . 13 V/μs Typ
- Wide Supply Voltage Range ±3 V to ±20 V
- Low Harmonic Distortion
- Designed to Be Interchangeable With Signetics NE5534, NE5534A, SE5534, and SE5534A

#### description

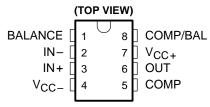
The NE5534, NE5534A, SE5534, and SE5534A are monolithic high-performance operational amplifiers combining excellent dc and ac characteristics. Some of the features include very low noise, high output drive capability, high unitygain and maximum-output-swing bandwidths, low distortion, and high slew rate.

These operational amplifiers are internally compensated for a gain equal to or greater than three. Optimization of the frequency response for various applications can be obtained by use of an external compensation capacitor between COMP and COMP/BAL. The devices feature input-protection diodes, output short-circuit protection, and offset-voltage nulling capability.

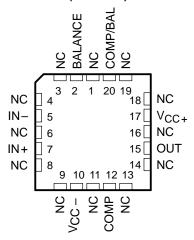
For the NE5534A, a maximum limit is specified for equivalent input noise voltage.

The NE5534 and NE5534A are characterized for operation from 0°C to 70°C. The SE5534 and SE5534A are characterized for operation over the full military temperature range of – 55°C to 125°C.

# NE5534, NE5534A . . . D OR P PACKAGE SE5534, SE5534A . . . . JG PACKAGE

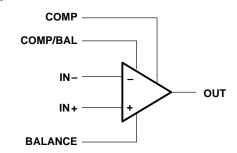


# SE5534, SE5534A . . . FK PACKAGE (TOP VIEW)



NC - No internal connection

#### symbol



SE5534A FROM TI NOT RECOMMENDED FOR NEW DESIGNS

#### **AVAILABLE OPTIONS**

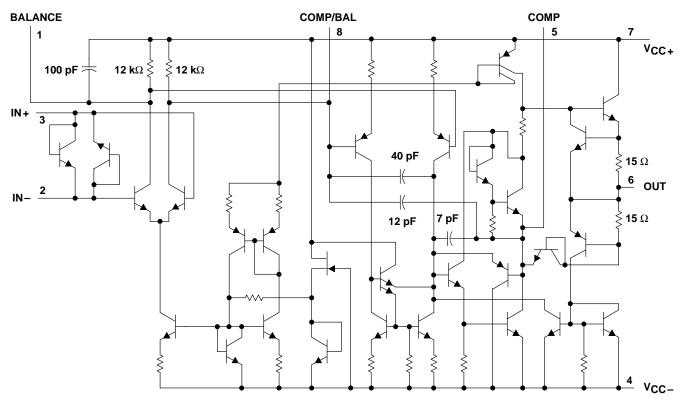
	V <sub>IO</sub> max	PACKAGE							
TA	AT 25°C	SMALL OUTLINE (D)	CERAMIC (FK)	CERAMIC DIP (JG)	PLASTIC DIP (P)				
0°C to 70°C	4 mV	NE5534D NE5534AD	_ _		NE5534P NE5534AP				
– 55°C to 125°C	2 mV	_	SE5534FK SE5534AFK	SE5534JG SE5534AJG	_				

The D package is available taped and reeled. Add the suffix R to the device type (e.g., NE5534DR).



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#### schematic



All component values shown are nominal.

Pin numbers shown are for D, JG, and P packages.

#### absolute maximum ratings over operating free-air temperature range (unless otherwise noted)

Supply voltage, V <sub>CC+</sub> (see Note 1)	
Supply voltage, V <sub>CC</sub> (see Note 1)	– 22 V
Input voltage either input (see Notes 1 and 2)	V <sub>CC+</sub>
Input current (see Note 3)	
Duration of output short circuit (see Note 4)	. unlimited
Continuous total power dissipation See Dissipation F	Rating Table
Operating free-air temperature range: NE5534, NE5534A	0°C to 70°C
SE5534, SE5534A – 55°	°C to 125°C
Storage temperature range – 65°	°C to 150°C
Case temperature for 60 seconds: FK package	260°C
Lead temperature range 1,6 mm (1/16 inch) from case for 60 seconds: JG package	300°C
Lead temperature range 1,6 mm (1/16 inch) from case for 10 seconds: D or P package	260°C

- NOTES: 1. All voltage values, except differential voltages, are with respect to the midpoint between V<sub>CC+</sub> and V<sub>CC-</sub>.
  - 2. The magnitude of the input voltage must never exceed the magnitude of the supply voltage.
  - 3. Excessive current will flow if a differential input voltage in excess of approximately 0.6 V is applied between the inputs unless some limiting resistance is used.
  - 4. The output may be shorted to ground or to either power supply. Temperature and/or supply voltages must be limited to ensure the maximum dissipation rating is not exceeded.



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#### **DISSIPATION RATING TABLE**

PACKAGE	T <sub>A</sub> ≤ 25°C POWER RATING	DERATING FACTOR ABOVE T <sub>A</sub> = 25°C	T <sub>A</sub> = 70°C POWER RATING	T <sub>A</sub> = 125°C POWER RATING
D	725 mW	5.8 mW/°C	464 mW	N/A
FK (see Note 5)	1375 mW	11.0 mW/°C	880 mW	275 mW
JG	1050 mW	8.4 mW/°C	672 mW	210 mW
Р	1000 mW	8.0 mW/°C	640 mW	N/A

NOTE 5: For the FK package, power rating and derating factor will vary with actual mounting technique used. The values stated here are believed to be conservative.

#### recommended operating conditions

	MIN	NOM MAX	UNIT
Supply voltage, V <sub>CC+</sub>	5	15	V
Supply voltage, V <sub>CC</sub> _	-5	<b>– 15</b>	V

### electrical characteristics, $V_{CC}$ $\pm$ = $\pm 15$ V, $T_A$ = $25^{\circ}C$ (unless otherwise noted)

PARAMETER		TEST CONDITIONS†		NE5534, NE5534A			SE5534, SE5534A			UNIT	
				MIN	TYP	MAX	MIN	TYP	MAX	ONIT	
V <sub>IO</sub>	Input offset voltage	V <sub>O</sub> = 0,	T <sub>A</sub> = 25°C		0.5	4		0.5	2	mV	
۷IO	input onset voltage	$R_S = 50 \Omega$	T <sub>A</sub> = Full range			5			3	IIIV	
lio	Input offset current	V <sub>O</sub> = 0	T <sub>A</sub> = 25°C		20	300		10	200	nA	
IIO	input onset current	VO = 0	T <sub>A</sub> = Full range			400			500		
lв	Input bias current	V <sub>O</sub> = 0	T <sub>A</sub> = 25°C		500	1500		400	800	nA	
אוי	input bias current	VO = 0	T <sub>A</sub> = Full range			2000			1500	ПА	
VICR	Common-mode input voltage range			±12	±13		±12	±13		V	
Vo (55)	Maximum peak-to-peak	R <sub>L</sub> ≥ 600 Ω	$V_{CC\pm} = \pm 15 \text{ V}$	24	26		24	26		V	
VO(PP)	output voltage swing	KL ≥ 000 22	$V_{CC\pm} = \pm 18 \text{ V}$	30	32		30	32		V	
۸. ه	Large-signal differential	$V_0 = \pm 10 \text{ V},$	T <sub>A</sub> = 25°C	25	100		50	100		V/mV	
AVD	voltage amplification	$R_L \ge 600 \Omega$	T <sub>A</sub> = Full range	15			25			V/mV	
Δ.	Small-signal differential voltage amplification	f = 10 kHz	$C_C = 0$		6			6		V/mV	
A <sub>vd</sub>			$C_C = 22 pF$		2.2			2.2			
	Maximum-output-swing bandwidth	$V_0 = \pm 10 \text{ V},$	CC = 0		200			200			
ВОМ		$V_0 = \pm 10 \text{ V},$	$C_C = 22 pF$		95			95		. kHz	
Olvi		$V_{CC\pm} = \pm 18 \text{ V},$ $R_L \ge 600 \Omega,$	$V_{O} = \pm 14 \text{ V},$ $C_{C} = 22 \text{ pF}$		70			70			
B <sub>1</sub>	Unity-gain bandwidth	$C_C = 22 pF$ ,	C <sub>L</sub> = 100 pF		10			10		MHz	
rį	Input resistance			30	100		50	100		kΩ	
z <sub>O</sub>	Output impedance	$A_{VD} = 30 \text{ dB},$ $C_{C} = 22 \text{ pF},$	$R_L \ge 600 \Omega$ , $f = 10 \text{ kHz}$		0.3			0.3		Ω	
CMRR	Common-mode rejection ratio	$V_O = 0$ , $R_S = 50 \Omega$	V <sub>IC</sub> = V <sub>ICR</sub> min,	70	100		80	100		dB	
ksvr	Supply voltage rejection ratio (ΔV <sub>CC</sub> /ΔV <sub>IO</sub> )	$V_{CC+} = \pm 9 \text{ V to} $ $V_{O} = 0,$	±15 V, R <sub>S</sub> = 50 Ω	80	100		86	100		dB	
los	Output short-circuit current				38			38		mA	
loo	Supply current	$V_{O} = 0$ ,	T <sub>A</sub> = 25°C		4	8		4	6.5	m^	
ICC		No load	T <sub>A</sub> = Full range						9	mA	

<sup>†</sup> All characteristics are measured under open-loop conditions with zero common-mode input voltage unless otherwise specified. Full range is T<sub>A</sub> = 0°C to 70°C for NE5534 and NE5534A and – 55°C to 125°C for SE5534 and SE5534A.



### NE5534, NE5534A, SE5534, SE5534A LOW-NOISE OPERATIONAL AMPLIFIERS

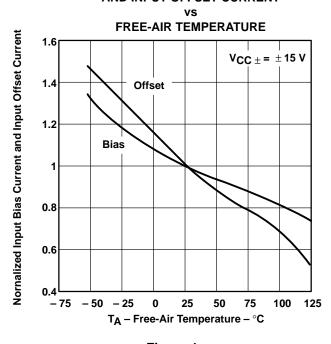
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### operating characteristics, $V_{CC} \pm = \pm 15 \text{ V}$ , $T_A = 25^{\circ}\text{C}$

PARAMETER		TEST CONDITIONS		SE5534, NE5534			SE5534A, NE5534A			UNIT
				MIN	TYP	MAX	MIN	TYP	MAX	UNIT
SR	Slew rate at unity gain	CC = 0	C = 0		13		13			V/µs
SIX		$C_C = 22 pF$			6			6		ν/μ5
t <sub>r</sub>	Rise time	$V_{I} = 50 \text{ mV},$	A <sub>VD</sub> = 1, C <sub>C</sub> = 22 pF,	20			20			ns
	Overshoot factor	$R_L = 600 \Omega,$ $C_L = 100 pF$			20%			20%		
t <sub>r</sub>	Rise time	$V_{I} = 50 \text{ mV},$			50			50		ns
	Overshoot factor	$R_L = 600 \Omega$ , $C_L = 500 pF$	$C_C = 47 \text{ pF},$		35%			35%		
\ \ \ \ \ \ \ \ \ \ \ \ \ \ \ \ \ \ \	Equivalent input noise voltage	f = 30 Hz	= 30 Hz		7			5.5	7	->4/ <del>11-</del>
V <sub>n</sub>	Equivalent input noise voltage	f = 1 kHz			4			3.5	4.5	nV/√Hz
Ţ.	Eminated in a training and a	f = 30 Hz			2.5			1.5		A / /
l <sub>n</sub>	Equivalent input noise current	f = 1 kHz		0.6		0.4			pA/√Hz	
F	Average noise figure	$R_S = 5 k\Omega$ ,	f = 10 Hz to 20 kHz					0.9		dB

#### TYPICAL CHARACTERISTICS<sup>†</sup>

# NORMALIZED INPUT BIAS CURRENT AND INPUT OFFSET CURRENT



#### Figure 1

#### **MAXIMUM PEAK-TO-PEAK OUTPUT VOLTAGE**

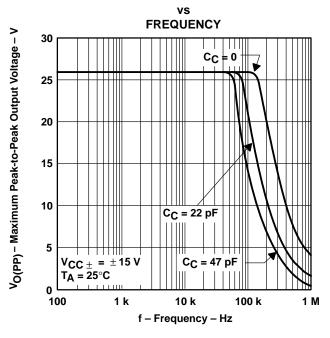


Figure 2

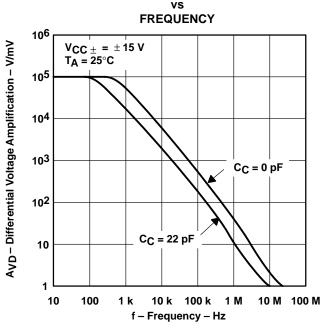
<sup>†</sup> Data at high and low temperatures are applicable only within the rated operating free-air temperature ranges of the various devices.



#### TYPICAL CHARACTERISTICS<sup>†</sup>

## LARGE-SIGNAL **DIFFERENTIAL VOLTAGE AMPLIFICATION FREQUENCY** 106 $V_{CC\pm} = \pm 15 V$ $T_A = 25^{\circ}C$ 10<sup>5</sup> 104 103 $C_C = 0 pF$ 102 C<sub>C</sub> = 22 pF 10 10 100 10 k 100 k 10 M 100 M

Figure 3



**NORMALIZED SLEW RATE AND** 

**UNITY-GAIN BANDWIDTH** 

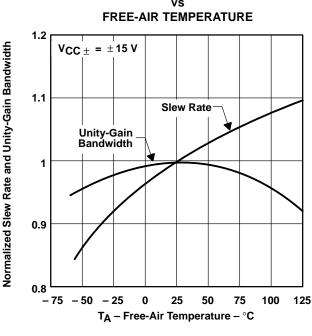


Figure 5

# **NORMALIZED SLEW RATE AND UNITY-GAIN BANDWIDTH**

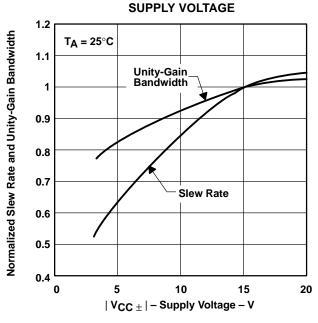


Figure 4

# TOTAL HARMONIC DISTORTION

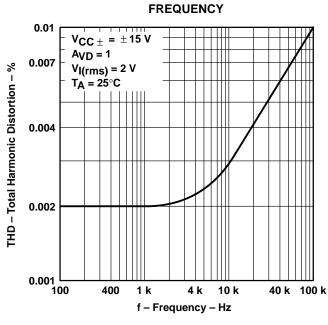
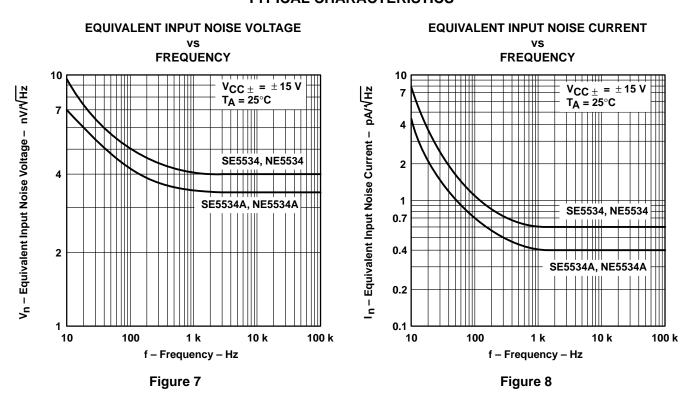


Figure 6

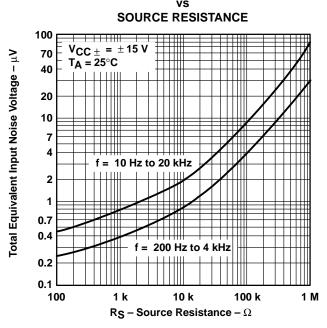
† Data at high and low temperatures are applicable only within the rated operating free-air temperature ranges of the various devices.



#### **TYPICAL CHARACTERISTICS**



## TOTAL EQUIVALENT INPUT NOISE VOLTAGE



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